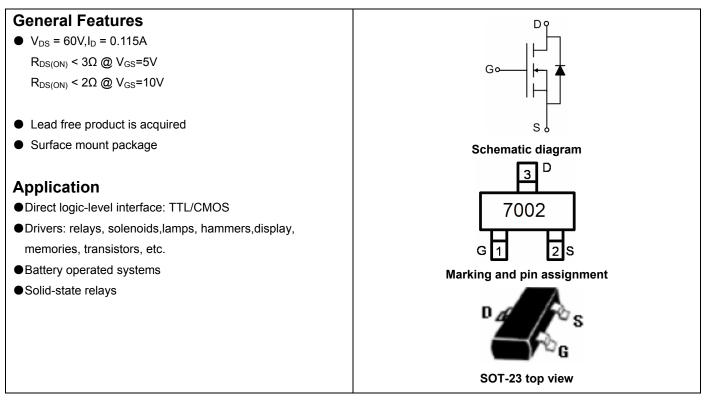




NCE N-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

U	0	0			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
7002	2N7002	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (TC=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous@ Current-Pulsed (Note 1)	I _D	0.115	A
Drain Current-Continuous@ Current-Pulsed	I _{DM}	0.8	A
Maximum Power Dissipation	PD	0.2	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2) R _{8JA} 625 °C/W				
	Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ extsf{ heta}JA}$	625	°C/W

Electrical Characteristics (TC=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V I _D =250µA	60	68	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =60V, V_{GS} =0V	-	-	1	μA



Pb Free Product

2N7002

Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			1			
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1	1.7	2.5	V
Drain-Source On-State Resistance	Rds(on)	V _{GS} =5V, I _D =0.05A	-	1.3	3	Ω
Drain-Source On-State Resistance		V _{GS} =10V, I _D =0.5A	-	1.1	2	Ω
Forward Transconductance	g fs	V _{DS} =10V,I _D =0.2A	0.08	-	-	S
Dynamic Characteristics (Note4)		·				
Input Capacitance	C _{lss}	V _{DS} =30V,V _{GS} =0V,	-	20	50	PF
Output Capacitance	C _{oss}	$V_{DS}=30V, V_{GS}=0V,$ F=1.0MHz	-	10	20	PF
Reverse Transfer Capacitance	C _{rss}		-	3.6	5	PF
Switching Characteristics (Note 4)		·	•			
Turn-on Delay Time	t _{d(on)}		-	10	-	nS
Turn-on Rise Time	tr	V _{DD} =30V,I _D =0.2A	-	50	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =10 Ω	-	17	-	nS
Turn-Off Fall Time	t _f		-	10	-	nS
Total Gate Charge	Qg	V _{DS} =10V,I _D =0.115A, V _{GS} =4.5V	-	1.7	3	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =0.115A	-	-	1.2	V
Diode Forward Current (Note 2)	ls		-	-	0.115	А

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production





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Typical Electrical and Thermal Characteristics

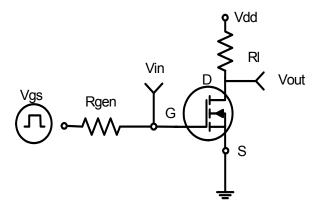
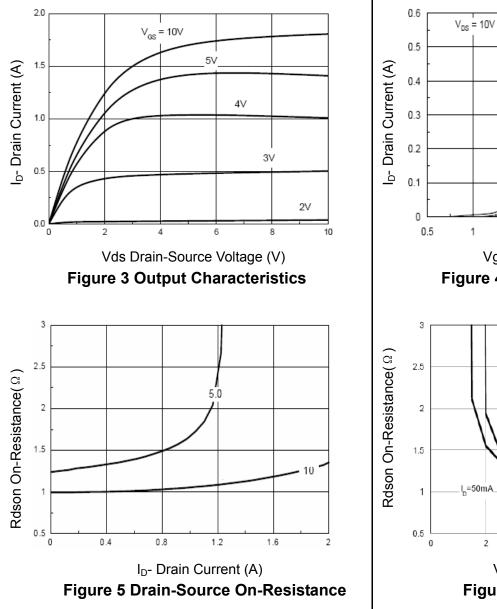
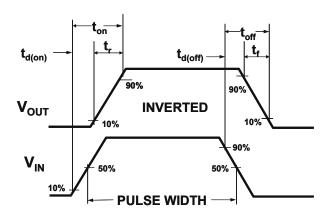


Figure 1:Switching Test Circuit







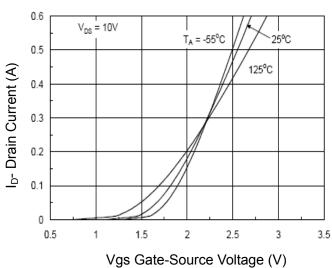
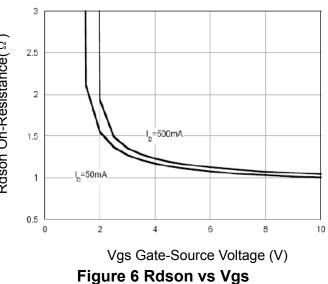


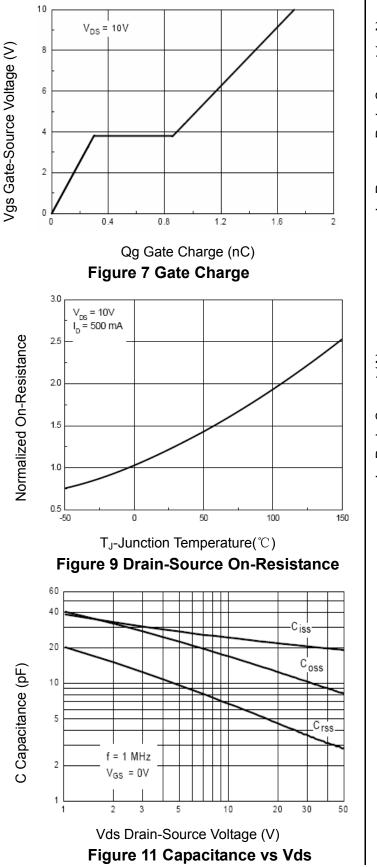
Figure 4 Transfer Characteristics

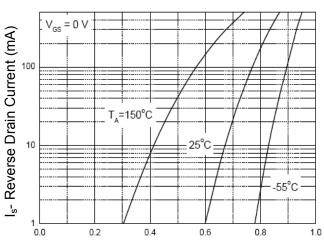




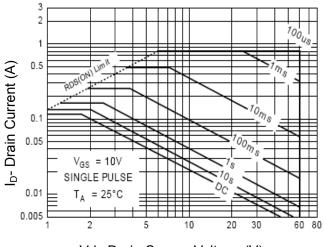


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Vsd Source-Drain Voltage (V) Figure 8 Source-DrainDiode Forward



Vds Drain-Source Voltage (V) Figure 10 Safe Operation Area







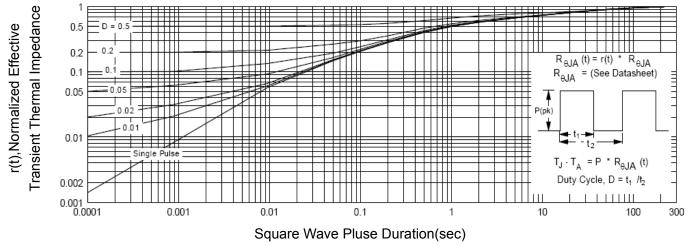
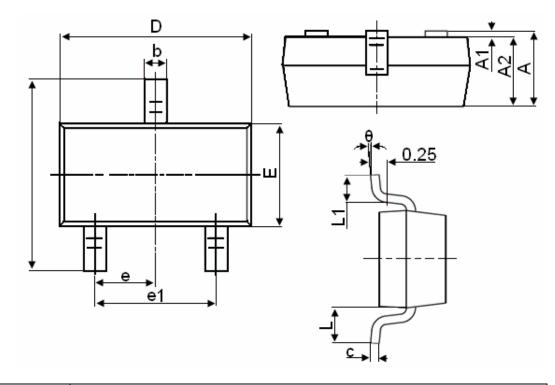


Figure 12 Normalized Maximum Transient Thermal Impedance





SOT-23 Package Information



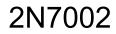
Symbol		Dimensions in Millimeters		
Symbol	MIN.	MAX.		
A	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
с	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е		0.950TYP		
e1	1.800	2.000		
L		0.550REF		
L1	0.300	0.500		
θ	0°	8°		

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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